DATA SHEET

рнотосоирсев PS2513-1,PS2513L-1

HIGH-SPEED SWITCHING/HIGH ISOLATION VOLTAGE PHOTOCOUPLER SERIES

-NEPOC Series-

DESCRIPTION

The PS2513-1 and PS2513L-1 are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor.

The PS2513-1 is in a plastic DIP (Dual In-line Package) and the PS2513L-1 is lead bending type (Gull-wing) for surface mount.

FEATURES

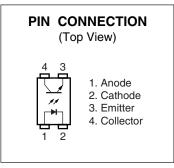
- High isolation voltage (BV = 5 000 Vr.m.s.)
- High collector to emitter voltage (VCEO = 120 V)
- Guaranteed maximum switching speed
 - (torf \leq 60 μ s @ IF = 5 mA, Vcc = 5 V, RL = 1.9 k Ω)
- High-speed switching (ton = 5 μ s TYP. @ IF = 5 mA, Vcc = 5 V, RL = 1.9 k Ω)

$$t_{\rm toff} = 25 \ \mu s \ \text{TYP.} \ @ \ \text{IF} = 5 \ \text{mA}, \ \text{Vcc} = 5 \ \text{V}, \ \text{RL} = 1.9 \ \text{k}\Omega$$

- <R> Ordering number of tape product: PS2513L-1-F3: 2 000 pcs/reel
- <R> Safety standards
 - UL approved: No. E72422
 - DIN EN60747-5-2 (VDE0884 Part2) approved: No. 40008862 (Option)

APPLICATIONS

- Power supply
- Air conditioner
- FA equipment

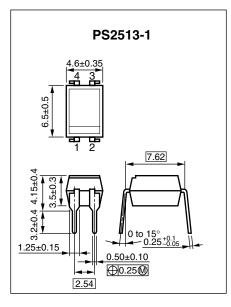


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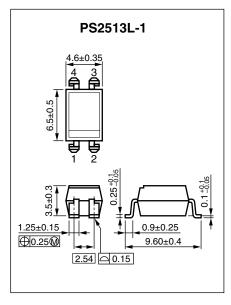
The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

<R> PACKAGE DIMENSIONS (UNIT: mm)





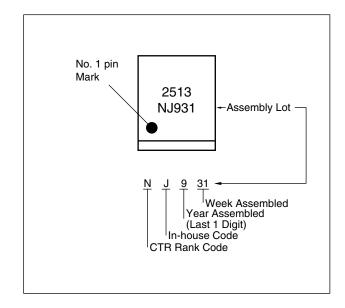
Lead Bending Type



<R> PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	7 mm
Outer Creepage Distance	7 mm
Inner Creepage Distance	3.5 mm
Isolation Thickness	0.2 mm

<R> MARKING EXAMPLE



<R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number ^{⁺1}
PS2513-1	PS2513-1-A	Pb-Free	Magazine case 100 pcs	Standard products	PS2513-1
PS2513L-1	PS2513L-1-A			(UL Approved)	
PS2513L-1-F3	PS2513L-1-F3-A		Embossed Tape 2 000 pcs/reel		
PS2513-1-V	PS2513-1-V-A		Magazine case 100 pcs	DIN EN60747-5-2	
PS2513L-1-V	PS2513L-1-V-A			(VDE0884 Part2)	
PS2513L-1-V-F3	PS2513L-1-V-F3-A		Embossed Tape 2 000 pcs/reel	approved products	
				(Option)	

*1 For the application of the Safety Standard, following part number should be used.

Symbol Ratings Unit Parameter 6 V Diode **Reverse Voltage** V_{R} Forward Current (DC) IF 60 mΑ mW/°C **Power Dissipation Derating** $\Delta P_D / ^{\circ}C$ 1.5 mW **Power Dissipation** \mathbf{P}_{D} 150 Peak Forward Current¹ **I**FP 1 А ٧ Transistor 120 Collector to Emitter Voltage VCEO Emitter to Collector Voltage 6 V V_{ECO} **Collector Current** lc 30 mΑ mW/°C ⊿Pc/°C 1.5 **Power Dissipation Derating Power Dissipation** Pc 150 mW Isolation Voltage*2 ΒV 5 000 Vr.m.s. **Operating Ambient Temperature** ΤA -55 to +100 °C -55 to +150 °C Storage Temperature Tstg

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

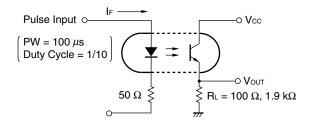
***1** PW = 100 μs, Duty Cycle = 1%

*2 AC voltage for 1 minute at $T_A = 25^{\circ}$ C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

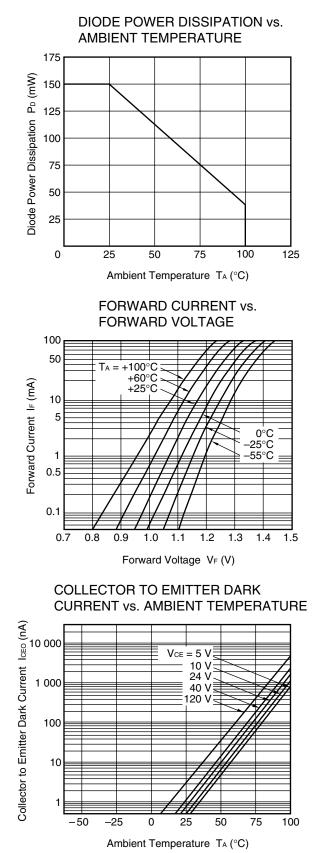
	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	I⊧ = 5 mA		1.1	1.3	V
	Reverse Current	IR	V _R = 5 V			5	μA
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		30		pF
Transistor	Collector to Emitter Dark Current	Iceo	Vce = 120 V, IF = 0 mA			100	nA
Coupled	Current Transfer Ratio	CTR1	IF = 1 mA, VCE = 5 V	25	75	100	%
	(Ic/IF)	CTR2	IF = 5 mA, VCE = 5 V	50	125	200	%
	Collector Saturation Voltage	VCE (sat)	IF = 10 mA, Ic = 2 mA			0.3	V
	Isolation Resistance	R ⊦o	VI-O = 1.0 kVDC	10 ¹¹			Ω
	Isolation Capacitance	CI-O	V = 0 V, f = 1.0 MHz		0.5		pF
	Rise Time ^{*1}	tr	V_{CC} = 5 V, Ic = 2 mA, RL = 100 Ω		3		μs
	Fall Time ^{*1}	tr			4		
	Turn-on Time ^{*1}	ton	V_{CC} = 5 V, I _F = 5 mA, R _L = 1.9 k Ω		5	60	μs
	Turn-off Time ^{*1}	toff			25	60	

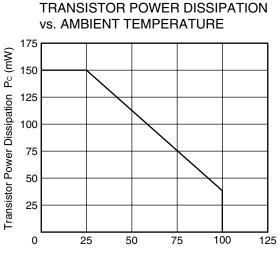
ELECTRICAL CHARACTERISTICS (TA = 25°C)

*1 Test circuit for switching time



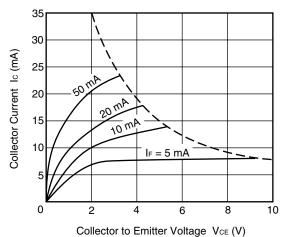
TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)



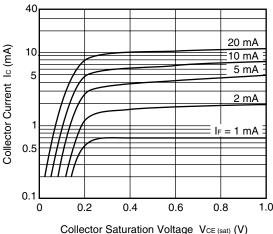


Ambient Temperature TA (°C)

COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

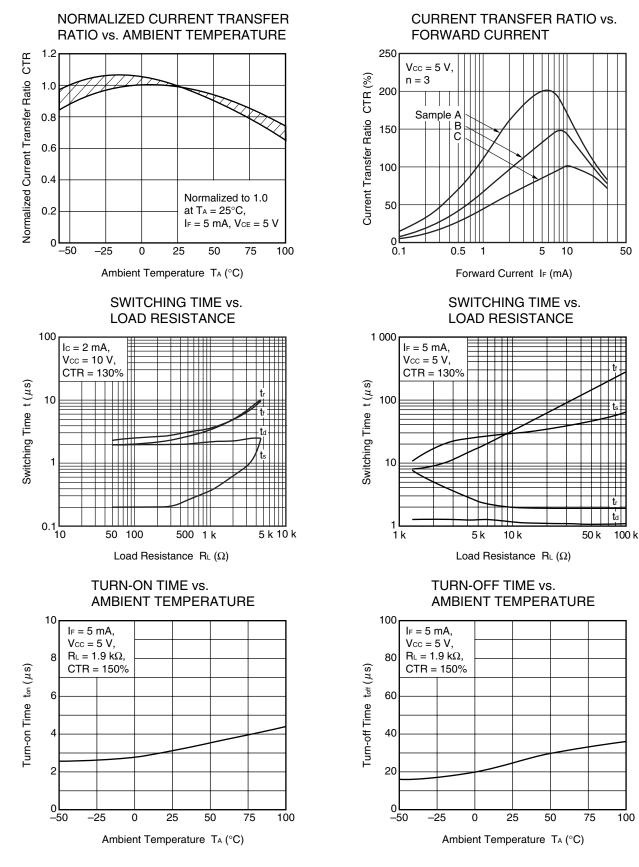


COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



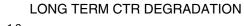
Remark The graphs indicate nominal characteristics.

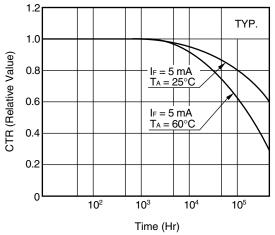
50



Remark The graphs indicate nominal characteristics.

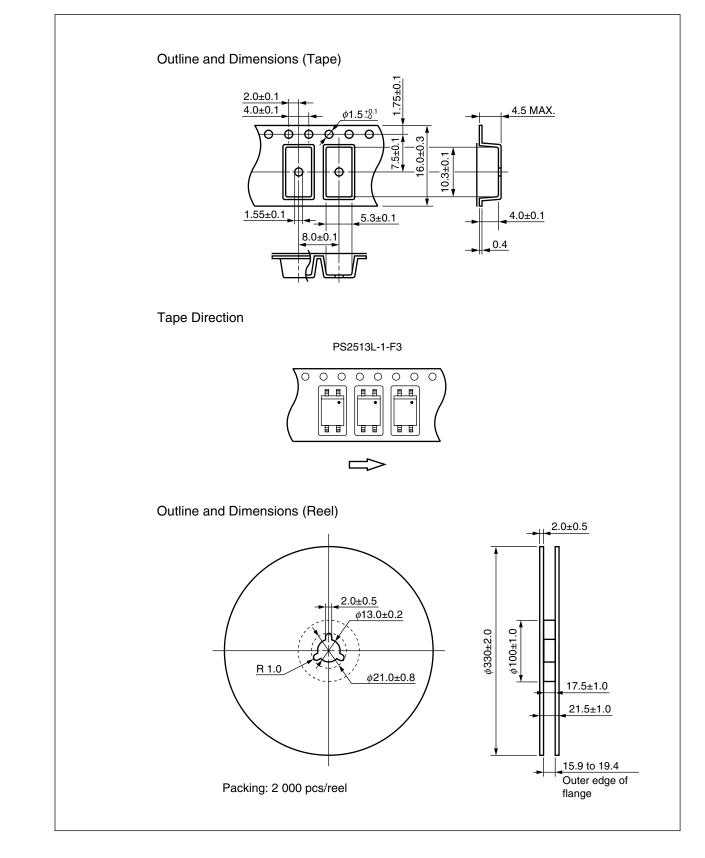
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Remark The graph indicates nominal characteristics.

<R> TAPING SPECIFICATIONS (UNIT: mm)



NOTES ON HANDLING

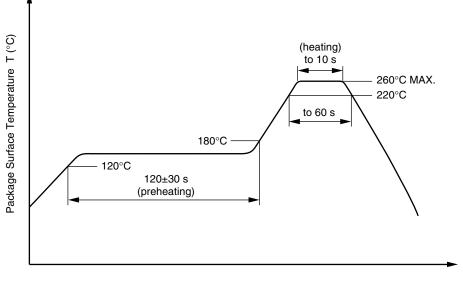
1. Recommended soldering conditions

(1) Infrared reflow soldering

- Peak reflow temperature
- Time of peak reflow temperature
- Time of temperature higher than 220°C
- Time to preheat temperature from 120 to 180°C
- Number of reflows
- Flux

260°C or below (package surface temperature) 10 seconds or less 60 seconds or less 120±30 s Three Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by soldering iron

Peak temperature (lead part temperature)	350°C or below
 Time (each pins) 	3 seconds or less
• Flux	Rosin flux containing small amount of chlorine (The flux with a
	maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead.
- (b) Please be sure that the temperature of the package would not be heated over 100°C.

(4) Cautions

• Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.

<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Speck	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.5 \times U_{IORM}$, $P_d < 5 \text{ pC}$	Uiorm Upr	890 1 335	V _{peak} V _{peak}
Test voltage (partial discharge test, procedure b for all devices test) U_{pr} = 1.875 × U _{IORM} , Pd < 5 pC	Upr	1 669	V _{peak}
Highest permissible overvoltage	Utr	8 000	Vpeak
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
Storage temperature range	Tstg	–55 to +150	°C
Operating temperature range	TA	–55 to +100	°C
Isolation resistance, minimum value $V_{IO} = 500 \text{ V dc at } T_A = 25^{\circ}\text{C}$ $V_{IO} = 500 \text{ V dc at } T_A \text{ MAX. at least } 100^{\circ}\text{C}$	Ris MIN. Ris MIN.	10 ¹² 10 ¹¹	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current IF, $Psi = 0$) Power (output or total power dissipation)	Tsi Isi Psi	175 400 700	°C mA mW
Isolation resistance $V_{IO} = 500 \text{ V dc at } T_A = 175^{\circ}C \text{ (Tsi)}$	Ris MIN.	10 [°]	Ω

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	 Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	• Do not burn, destroy, cut, crush, or chemically dissolve the product.
	• Do not lick the product or in any way allow it to enter the mouth.

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